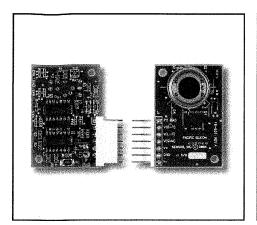
NI USB∙	-6008	α.	New GPD
GND AI 0/AI 0+ AI 4/AI 0- GND AI 1/AI 1+ AI 5/AI 1- GND AI 2/AI 2+ AI 6/AI 2- GND	1 17 2 18 3 19 4 20 5 21 6 22 7 23 8 24 9 25 10 28	P0.0 P0.1 P0.2 P0.3 P0.4 P0.5 P0.6 P0.7 P1.0 P1.1	Pacific Silicon Cemos  OP 50-6-18n-SD2  ThorLabs PDa80A
A13/A13+ A17/A13+ GND A00 A01 GND	11 27 12 28 13 29 14 30 15 31 16 32	P1.2 P1.3 PFI 0 +2.5 V +5 V GND	NI USB 600B

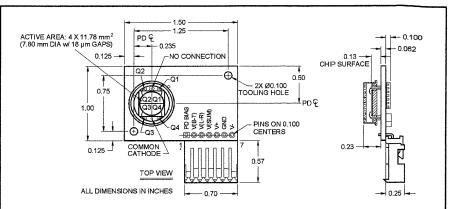
Paver GIND 2P-50-6-18W-502 96 R USB 6008 O IBLV BARE 0 1,4,7,6ND bias 1 ONC PUR 1+4-/2+8) 2 O 5 AII (1/2) GBN 1+2-(314)3 0 8 AIZ (SUM) 1+2+3+4 4 AJS should BRY be set to ACE, ±9V



# Pacific Silicon Sensor Series 6 Data Sheet Quad Sum and Difference Amplifier

Part Description QP50-6-18u-SD2 Order # 10-027





#### DESCRIPTION

The QP50-6-18u-SD2 is a quad photodiode array with current-to-voltage amplifiers that provide bottom minus top and left minus right difference signals. Additionally the QP50-6-18u-SD2 provides a signal that is the sum of all four quadrant diode signals. The difference signals are voltage analogs of the light intensity difference sensed by the pairs of photodiode elements in the array. The board has a 7 pin connector attached for easy hook up.

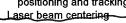
#### **OPTIONS**

- Can be purchased without connector, use order # 10-007.
- For alternate gap size, see data sheet QP50-6SD2 for 42 μm gap version.

Also available with quad detector active area sizes ranging from 1mm<sup>2</sup> to 20 mm<sup>2</sup>

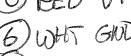
#### APPLICATIONS

NIR & visible pulsed light positioning and tracking







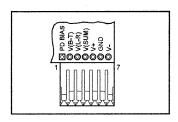


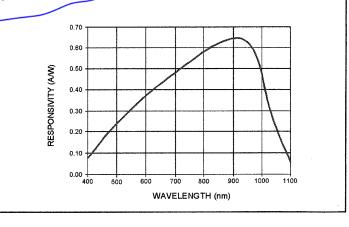
F) YEL V-

### ABSOLUTE MAXIMUM RATING

SYMBOL	PARAMETER	MIN	MAX	UNITS
T <sub>STG</sub>	Storage Temp	-15	+100	90
T <sub>OP</sub>	Operating Temp	0	+70	°C
Vs	Power Supply Voltage Recommended ±15V	±4.5	±18	V
$V_R$	Applied Bias Voltage*	0	15	V

#### CONNECTIONS





#### **ELECTRO-OPTICAL CHARACTERISTICS @ 22° C**

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
\/	Output Valtage (all sutputs)			+V <sub>s</sub> -3		\ \/
V <sub>O</sub> Output V	Output Voltage (all outputs)		T	-V <sub>s</sub> +3		V
lo	Output Current Limit	V <sub>s</sub> = ± 15 V; V <sub>R</sub> = 0 V			25	mA
	Slew Rate	$V_s = \pm 15 \text{ V}; V_R = 0 \text{ V}$			10	V/μs
	Theoretical noise	$V_s = \pm 15 \text{ V}; V_R = 0 \text{ V}$		15		nV/√Hz
$\Delta f$ -3dB	Bandwidth**	$V_s = \pm 15 \text{ V}; V_R = 5 \text{ V}; \lambda = 880 \text{ nm}$		250		kHz

PINOUT

Disclaimer: Due to our policy of continued development, specifications are subject to change without notice.

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<sup>\*</sup> actual bias voltage to photodiode: pad 1 voltage times 0.91. Do not apply negative voltages to pad 1.

<sup>\*\*</sup> dependant on bias voltage

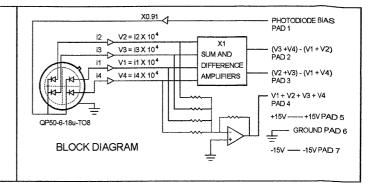
The **QP50-6-18u-SD2** outputs are labeled as B-T for bottom minus top, L-R for left minus right. The output voltages are obtained by routing the diode element currents into current-to-voltage amplifiers with a gain of 10<sup>4</sup>:

 $V_{B-T} = [(I_{3,4}) - (I_{1,2})] \bullet (10^4)$  on Pad 2.

 $V_{L-R} = [(I_{2,3}) - (I_{1,4})] \cdot (10^4)$  on Pad 3.

 $V_{SUM} = [(I_{1,2,3,4}) \cdot (10^4) \text{ on Pad 4}.$ 

I  $_{X,Y}$  is the sum of the currents generated by photodiode elements x and y. Looking down through the window of the photodiode, the quadrants are identified in drawing on page one.



#### APPLICATION NOTES

#### Beam Size

The light spot applied to the QP50-6-18u-SD2 must be smaller than the diameter of the quadrant photodiode array. The detector active area has a diameter of 7.8 millimeters. If the light spot is too large, it may be reduced to fit the photodiode array by use of a lens. A decrease in output signal strength is observed as the light spot crosses the separation boundary of the quadrants, usually referred to as the "gap". This effect is more pronounced as the diameter of the light spot decreases, as a larger percentage of the light spot's power falls within the non-active gap. For this reason, the minimum light beam diameter should be a least one millimeter. A lens may be used to increase the beam diameter.

#### **Photodiode Bias Operation**

The QP50-6-18u-SD2 array may be operated either in the zero bias or the reverse bias mode. Pin 1 is connected, via a resistor divider, to the non-inverting input of a voltage follower operational amplifier. This line may be left unterminated, grounded or connected to a voltage source of zero volts to operate in the zero bias mode. If the photodiode bias line is connected to a positive voltage source (but less than Vcc), then the photodiode elements in the array will be biased at 0.91 x VBias. Do not connect Pin 1 to negative voltages, as this will forward bias the photodiode array, making it inoperable and possibly damaging the circuit.

#### Use of Sum and Difference Signals for Alignment

The sum output signal may be used to help preliminary alignment of the QP50-6-18u-SD2 to the source light beam. First, the beam or the QP50-6-18u-SD2 is adjusted for maximum sum output signal. Second, the beam or QP50-6-18u-SD2 is adjusted until the L-R and B-T signals are at minimum. This procedure results in the beam being centered on the quad photodiode array.

#### Signal Null Detector for Servo Applications

A common application for the QP50-6-18u-SD2 is a signal null detector as part of a servo system that maintains the position of a light beam. Errors in beam position are reported by the QP50-6-18u-SD2 and may be used to adjust a positioning device that restores the beam or the beam's source to a null position.

#### Speed of Response

Increasing the photodiode bias voltage will increase the speed of the QP50-6-18u-SD2. Operating with zero reverse bias is sufficient for many applications (-3dB is around 150 kHz at 880 nm). As noted above, Pin 1 is provided for applying positive bias voltage to the quad for higher frequency response. Care should be taken not to exceed the circuit common mode values and the breakdown voltage of the quad photodiode. See Absolute Maximum Ratings on page one for maximum values.

#### **Temperature Considerations**

The operation temperature must be between 0 to 70 °C. For best resolution the temperature should be kept at or below 25 °C. Thermal gradients across the detector will cause position errors and should be avoided.

#### Offsets

Precision components are used in the circuitry but as much as 10 millivolts of dark offset may still be present in the outputs. If this causes a problem the offsets should be removed externally.

#### USA:

7/10/2009

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Table 4 lists the analog terminal assignments, and Table 5 lists the digital terminal assignments.

Table 4. Analog Terminal Assignments

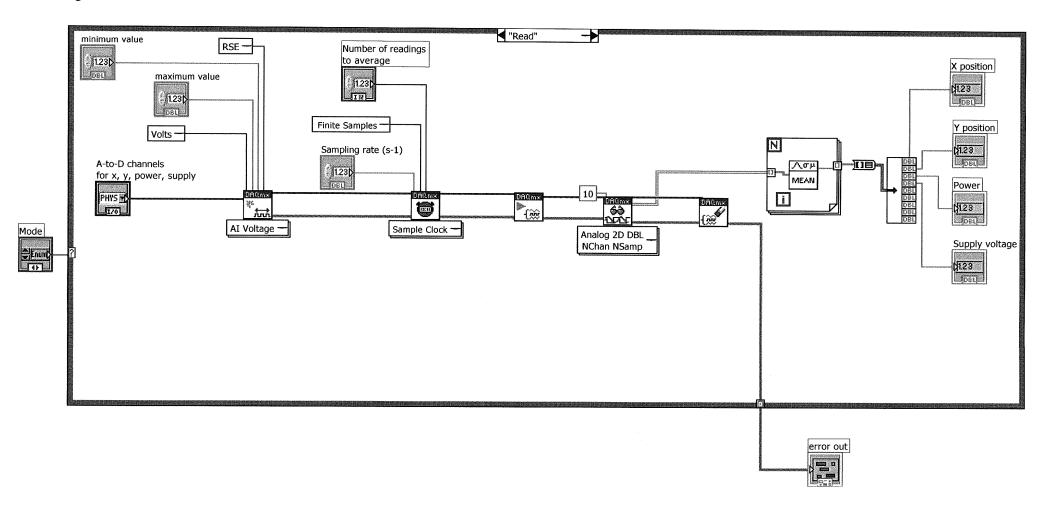
Module	Terminal	Signal, Single-Ended Mode	Signal, Differential Mode
	1	GND	GND
	2	AI 0	AI 0+
	3	AI 4	AI 0-
	4	GND	GND
1 2	5	AI 1	AI 1+
3 4	6	AI 5	AI 1
5	7	GND	GND
6 7	8	AI 2	AI 2+
8 9	9	AI 6	AI 2
	10	GND	GND
12 1	11	AI 3	AI 3+
3 14	12	AI 7	AI 3
15 16	13	GND	GND
	14	AO 0	AO 0
	15	AO 1	AO 1
	16	GND	GND

NI A/D

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Block Diagram



# **Reference and Power Sources**

The NI USB-6008/6009 creates an external reference and supplies a power source. All voltages are relative to COM unless otherwise noted.

### +2.5 External References

The NI USB-6008/6009 creates a high-purity reference voltage supply for the ADC using a multi-state regulator, amplifier, and filter circuit. You can use the resulting +2.5 V reference voltage as a signal for self test.

## +5 V Power Source

The NI USB-6008/6009 supplies a 5 V,  $200\ mA$  output. You can use this source to power external components.



Note While the device is in USB suspend, the output is disabled.

# **Specifications**

The following specifications are typical at 25 °C, unless otherwise noted.

Converter type ......Successive approximation

# **Analog Input**

Analog inputs	8 single-ended, 4 differential, software selectable
Input resolution	
NI USB-6008	12 bits differential,
	11 bits single-ended
NI USB-6009	14 bits differential,
	13 bits single-ended
Max sampling rate (aggregate) <sup>1</sup>	
NI USB-6008	10 kS/s
NI USB-6009	48 kS/s
AI FIFO	512 bytes
Timing resolution	41.67 ns (24 MHz timebase)

<sup>&</sup>lt;sup>1</sup> System dependent.

Input range

Single-ended .....±10 V

Differential..... $\pm 20 \text{ V}^1$ ,  $\pm 10 \text{ V}$ ,  $\pm 5 \text{ V}$ ,  $\pm 4 \text{ V}$ ,

±2.5 V, ±2 V, ±1.25 V, ±1 V

Working voltage.....±10 V

Input impedance ...... 144  $k\Omega$ 

Overvoltage protection.....±35

trigger

System noise<sup>2</sup>

Single-ended

±10 V range ...... 5 mVrms

Differential

±20 V range......5 mVrms

 $\pm 1\ V\ range \dots \dots 0.5\ mVrms$ 

Absolute accuracy at full scale, single-ended

Range	Typical at 25 °C (mV)	Maximum over Temperature (mV)
±10	14.7	138

#### Absolute accuracy at full scale, differential<sup>3</sup>

Range	Typical at 25 °C (mV)	Maximum over Temperature (mV)
±20	14.7	138
±10	7.73	84.8
±5	4.28	58.4
±4	3.59	53.1
±2.5	2.56	45.1

<sup>1 ±20</sup> V means that |Al+ - (Al-)| <= 20 V. However, Al+ and Al- must both be within ±10 V of GND. Refer to the Connecting Differential Voltage Signals for more information.

<sup>&</sup>lt;sup>2</sup> System noise measured at maximum sample rate.

<sup>&</sup>lt;sup>3</sup> Input voltages may not exceed the working voltage range.